NSN 5961-01-369-9625

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-369-9625 **Inclosure Material:** Glass and plastic **Overall Length:** Between 4.699 inches and 5.207 inches **Overall Diameter:** Between 2.413 inches and 2.667 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 reverse voltage, peak and 35.0 forward voltage, dc **Current Rating Per Characteristic:** 30.00 amperes peak forward surge current and 1.00 amperes peak forward surge current **Capacitance Rating In Picofarads:** 15.0 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure: Demilitarization:** No